millimeter-wave electronic systems. They are found in com- not be adapted for microwaves and millimeter waves, and mercial and military equipment, including receiving, trans- once the idea caught on, there was no turning back. Micromitting, and dual-purpose systems. Circulators are used in wave monolithic integrated circuits (MMICs) became the next ship, satellite, aircraft and land-based equipment. Because all technology revolution.
of this equipment has been under ever increasing pressure to Fabrication of circulators in the hybrid format began in of this equipment has been under ever increasing pressure to Fabrication of circulators in the hybrid format began in
hecome lighter smaller, and more reliable over the last three the 1960s and 1970s, and included such str become lighter, smaller, and more reliable over the last three the 1960s and 1970s, and included such structures as ferrite
decades coinciding with the semiconductor and integrated devices prepared by dropping a ferrite pu decades, coinciding with the semiconductor and integrated devices prepared by dropping a ferrite puck into a hole ma-
circuit revolutions in technology microwaye and millimeter. chined into a substrate material, metallizin circuit revolutions in technology, microwave and millimeter- chined into a substrate material, metallizing the shield and wave components have converted from hollow or partly filled microstrip lines, and then placing the whole assembly in a
waveguiding structures to these compatible with planar con housing. This concept extended itself in the waveguiding structures to those compatible with planar con-
figures into having the circulator device prepared on the same sub-
figures into having the circulator device prepared on the same sub-

To eliminate the many problems associated with hybrid 1960s onward for planar circulators, and all of these methods, circuit technology, an increasingly aggressive move toward including the boundary-element method, the fin circuit technology, an increasingly aggressive move toward including the boundary-element method, the finite-element monolithic integrated circuits (MICs) began in the late 1970s, method, and the finite-difference method, are amenable to an-
accelerated in the 1980s, and became mature in the 1990s. alvaing devices with arbitrary or ponst accelerated in the 1980s, and became mature in the 1990s. alyzing devices with arbitrary or nonstandard perimeters, but
The basic idea behind this newer technology was to utilize the are extremely numerically intensive. Th The basic idea behind this newer technology was to utilize the are extremely numerically intensive. They have their place in advantages the semiconductor manufacturers had obtained in the suite of techniques employed to re advantages the semiconductor manufacturers had obtained in the suite of techniques employed to realize a final device, but
producing hundreds of thousands of miniature solid-state ac-
for user-friendly device design, where producing hundreds of thousands of miniature solid-state ac-
tive and passive components of exactly the same properties. are performed to find a final acceptable design with the tive and passive components of exactly the same properties. are performed to find a final acceptable design with the
They did it by using step-and-repeat fabrication techniques proper characteristics, it is most desirable They did it by using step-and-repeat fabrication techniques proper characteristics, it is most desirable to use a Green's
on single crystal silicon and gallium arsenide wafers of pre-
function method. Though the Green's fu cise thickness and uniform properties. The uniformity of the works only for a circular shape and some other simple canonisemiconductor wafers was assured by growing single crystal cal geometries, it can be used to good approximation for other, boules of the desired elemental or compound semiconductors. nonstandard shapes to obtain the basic design information Devices were fabricated by ion implanting, diffusing, or de- required before switching to the use of the costly and slow

NUMERICAL MODELING OF CIRCULATORS positing in or on the wafer the selected atoms, using vacuum chambers or furnaces.

Circulators are a key control component of microwave and There was no reason, in principle, why MIC methods could

Frame configuration enables the circuit designer to use a:

interhance of the circuit designer to use a:

interhance on the same sub-

the configuration enables the circuit designer to use a:

strate as other microwave an

two planar substrates in a housing having many of them. Other electromagnetic techniques were examined from the
To eliminate the many problems associated with hybrid 1960s onward for planar circulators, and all of these me function method. Though the Green's function technique

with the use of Green's-function-based computer codes. Since (3-D) Green's functions. the thickness of the substrate is a fraction of a wavelength, To find the complete electromagnetic field, dyadic Green's electric. Such condition forms are what is referred to as the are full $(E_x, E_y, E_z$ and H_x, H_y, H_z must be considered; equiva-
hard wall condition. For such a condition Green's functions lently, E_x, E_y, E_z and H_y, H_z , in c hard wall condition. For such a condition, Green's functions are available for both a homogeneous and an inhomogeneous 2-D ferrite puck. **FERRITE MATERIAL PARAMETERS AFFECTING MODELING**

The inhomogeneous case is very important, since the situation of nonuniformly applied magnetic bias field, finite-sized Nonreciprocity is generated in the circulator device (Fig. 1) by
nuck, and nonuniform ferrite material distribution through-
applying a bias dc magnetic field out the puck radius all lead to violation of the uniformity asdesign, it can actually be only a rough estimate or even a bad approximation if the magnetic bias nonuniformities become ment κ compared with the diagonal element μ will determine
large or if intentional variation of the ferrite material magnetic the extent of nonreciprocal ac nized that inhomogeneous Green's functions are required. Thus the uniform 2-D Green's function must be replaced in many circumstances by an inhomogeneous 2-D Green's function.

Whether the problem being addressed is uniform or nonuniform, the designer may be left with the need to assess the effect of the external dielectric medium. This can be done using a specially prepared Green's function that allows some leakage of the electromagnetic wave into the surrounding dielectric region, while maintaining the basic electromagnetic function of the device, which is to exchange energy between the multiport device terminals.

Green's functions that can represent circulator behavior for an arbitrary number of ports, with arbitrary angular locations along the device perimeter, exist even at present. But great economy of computational effort results if the distribution of the ports along the perimeter is manyfold symmetric. This is assured if the ports are chosen to be of equal angular width and placed regularly along the circumference of the de vice. Once this is done, the perimeter Green's functions, relations and the set of a microstrip circulator, valid for either a 2-D in a 3-D representation. In the 3-D case it represents a cross-section field at another po

(uniform versus inhomogeneous), the wall characteristic netic wall or a ferrite–dielectric interface.

numerically intensive solvers. Also, because the circular (hard wall versus soft wall), and the properties of ports (arbishape is very popular, oftentimes the use of the Green's func- trary versus symmetric disposition) apply equally well for tion method will provide the exact solution for design. two- and three-dimensional circulator models. As already mentioned, the 2-D model approach is quite reasonable for many if not most experimentally encountered situations. **COMPUTER-AIDED DESIGN OF PLANAR CIRCULATORS** However, where specific study of the substrate thickness effect of the circulator performance is desired, the designer Computer-aided design of ferrite circulators is made easy must resort to using rigorously derived three-dimensional

the higher-order perpendicular mode structure is limited, as function solutions must be sought and satisfactory forms obis the launching of surface waves. The lack of surface waves tained that will enable convenient representations for numeris desirable for maintaining a controllable mode structure in-
side the circulator, as well as in the input and output trans-
tric field component (E_z) and the magnetic field components side the circulator, as well as in the input and output trans-
mission lines, which can be microstrip or coplanar. The thin $(H_x, H_y$ or H_y, H_d in cylindrical coordinates) must be determission lines, which can be microstrip or coplanar. The thin $(H_x, H_y \text{ or } H_y, H_\phi \text{ in cylindrical coordinates})$ must be deter-
substrate also means that a 2-D representation of the electro-
mined by the driving function (or source). The source ma substrate also means that a 2-D representation of the electro- mined by the driving function (or source). The source may be magnetic fields within the circulator device is a reasonable a current vector (or its equivalent c magnetic fields within the circulator device is a reasonable a current vector (or its equivalent components), an electric
approximation. The device may be modeled be letting ways field vector, or a magnetic field vector on approximation. The device may be modeled be letting waves field vector, or a magnetic field vector on a contour or surface.

enter and exit through specific ports, and assuming that no. The source location exciting the cir enter and exit through specific ports, and assuming that no
energy excaps through the intervening perimeter contour respectively the model is 2-D, and on a surface if the model is 3-D. energy escapes through the intervening perimeter contour re-
gions between ports. This means that magnetic walls are as. For the 3-D model the dyadic Green's function is much more gions between ports. This means that magnetic walls are as-
sumed at interfaces between the ferrite and the external di-
external di-
external time complicated because the electric and magnetic field vectors
electric Such

puck, and nonuniform ferrite material distribution through- applying a bias dc magnetic field perpendicular to the planar
out the puck radius all lead to violation of the uniformity as- surface of the structure, be it hybr sumption. So although the uniform Green's function may be field will create off-diagonal tensor elements in the permeabil-
a decent first approximation on the way to getting a circulator ity, and these new elements are ant a decent first approximation on the way to getting a circulator ity, and these new elements are antisymmetrically disposed
design it can actually be only a rough estimate or even a had with respect to the diagonal. The siz ment κ compared with the diagonal element μ will determine

$$
\stackrel{\leftrightarrow}{\mu} = \mu_0 \begin{bmatrix} \mu & -j\kappa & 0 \\ j\kappa & \mu & 0 \\ 0 & 0 & 1 \end{bmatrix}
$$
 (1)

Iations to one another, vastly reducing the computer times for of symmetrically disposed ports (three here). Under the central shield running simulations of the circulator.
is the ferrite material. Microstrip lines provide All the above arguments relating to the nature of the puck environment. The inhomogeneous wall between ports is either a mag-

where μ_0 is the free-space value. μ and κ (relative values) have both real and imaginary parts when the system is lossy, magnetization field, allowing us to rewrite these two equaas is any real ferrite material. Thus, in phasor form (assum- tions as ing an e^{jωt} time dependence) we have by Soohoo (2)

$$
\mu = \mu' - j\mu'' \tag{2}
$$

$$
\kappa = \kappa' - j\kappa'' \tag{3}
$$

$$
\mu' = 1 + \frac{\omega_{\rm m}\omega_0[\omega_0^2 - \omega^2(1 - \alpha_{\rm m}^2)]}{[\omega_0^2 - \omega^2(1 + \alpha_{\rm m}^2)]^2 + 4\omega^2\omega_0^2\alpha_{\rm m}^2}
$$
(4a)

$$
\mu'' = \frac{\omega_{\rm m}\omega\alpha_{\rm m}[\omega_0^2 + \omega^2(1 + \alpha_{\rm m}^2)]}{[\omega_0^2 - \omega^2(1 + \alpha_{\rm m}^2)]^2 + 4\omega^2\omega_0^2\alpha_{\rm m}^2}
$$
(4b)

$$
\kappa' = -\frac{\omega_{\rm m}\omega[\omega_0^2 - \omega^2(1 + \alpha_{\rm m}^2)]}{\omega^2(1 - \omega_0^2)(1 + \omega_{\rm m}^2)^2}
$$
(5a)

$$
\begin{array}{ll}\n\kappa & = & \left[\omega_0^2 - \omega^2 (1 + \alpha_{\rm m}^2) \right]^2 + 4 \omega^2 \omega_0^2 \alpha_{\rm m}^2\n\end{array} \tag{64}
$$

$$
\kappa'' = -2 \frac{\omega_0 \omega^2 \alpha_m \omega_m}{[\omega_0^2 - \omega^2 (1 + \alpha_m^2)]^2 + 4\omega^2 \omega_0^2 \alpha_m^2}
$$
(5b)

Controlling variables in these equations are the magnetization radian frequency ω_m , ferromagnetic resonance radian frequency ω_0 , phenomenological damping term α_m , and operating quency ω_0 , phenomenological damping term α_m , and operating sity become an inhomogeneous boundary value and forcing radian frequency ω . The first three frequencies can be found function problem. In those situatio

$$
\omega_{\rm m} = -\gamma M \tag{6}
$$

$$
\omega_0 = -\gamma H_{\rm i} \tag{7}
$$

$$
\alpha_{\rm m} = -\frac{\gamma \Delta H}{2\omega} \tag{8}
$$

Oe. *M* is the magnetization, which may approach a saturated ^{to 19,500 Oe lead to a ferromagnetic frequency range f_0 (=} value M_s ; ΔH the ferromagnetic linewidth; and H_i the internal $\omega_0/2\pi$ from 47.6 GHz to 54.6 GHz. The anisotropy field is magnetic field which may be expressed as a superposition of derived from the anisotropy en magnetic field, which may be expressed as a superposition of derived from the anisotropy energy of the ferrite. It produces
the net internal field due to externally applied field H_{and} a torque on the magnetization in the net internal field due to externally applied field H_{ap} and

$$
H_{\rm i} = H_{\rm i(ap)} + H_{\rm an} \tag{9}
$$

$$
H_{i\text{(ap)}} = H_{\text{ap}} - 4\pi N_{zz}M\tag{10}
$$

M is assumed to be in the *z* direction also. When saturation has been attained, *M* is replaced by *M*_s. Of course, the resultant field is not necessarily only in the *z* direction even if the applied field is. Equation (10) represents then an approximation of further implications, other than its scalar form. In vector form, we have

$$
\boldsymbol{H}_{i(ap)} = \boldsymbol{H}_{ap} - 4\pi \boldsymbol{N} \cdot \boldsymbol{M} \tag{11}
$$

The demagnetization factor N_{zz} , which is a function of the radial location *r* within the circulator puck R ($r \leq R$), has the property

$$
N_{zz} = N_{zz}(r, z) \le 1 \tag{12}
$$

The last term in Eqs. (10) and (11) is referred to as the de-

(13a)
$$
H_{i(ap)} = H_{ap} - H_{de}
$$

$$
H_{\text{de}} = 4\pi N_{zz}M\tag{13b}
$$

$$
\boldsymbol{H}_{i(ap)} = \boldsymbol{H}_{ap} - \boldsymbol{H}_{de} \tag{14a}
$$

$$
\boldsymbol{H}_{\text{de}} = 4\pi \boldsymbol{N} \cdot \boldsymbol{M} \tag{14b}
$$

If it is desired to avoid the approximation implied by the designations in Eqs. (13b) and (14b), then the problem must be solved fully by numerical means, self-consistently obtaining the static field solution inside and outside the ferrite puck, whatever its geometric shape. This holds true whether the shape is a thin cylindrical volume, or a more irregular shape such as a hexagonal prism.

For finite-thickness puck, N_{zz} will be nonuniform, and this will make μ and κ also nonuniform, through Eqs. (4) and (5). Therefore we see that the circulator problem must by necesby bias field is applied to create saturation, $H_{\text{ap}} \approx H_{\text{de}}$ and their cancellation in Eq. (10) leads to $H_{i(\text{app})} \approx 0$. By Eq. (9), the net internal magnetic field H_i will be either $H_i \approx 0$ (ordinary ferrite material) or $H_i \approx H_{in}$ (hexagonal ferrite material). In fact, in a hexagonal ferrite, with $H_{ap} = 0$ and its remanent magnetization $\overline{M} = 0$, we have $H_{i(\text{ap})} = 0$ and $H_i = H_{\text{an}}$ holds exactly. Real hexagonal ferrites will have nonzero \overline{M} , making $H_i =$ Here γ is the gyromagnetic ratio, whose value in rationalized $H_{an} - H_{de} \approx H_{an}$. For hexagonal ferrites where no applied mag-
MKS units is -2.21265×10^5 (rad/s)/(A/m) = $2\pi \times 2.8$ MHz/
On M is the magnetization wh the anisotropy field *H*_{an}: remanent magnetization as the the same direction as the remanent magnetization.

One of the issues that must be understood is why these devices are not operated near or at the ferromagnetic reso-The internal magnetic bias field $H_{i(\text{ap})}$ has previously been ap-
proximated using a demagnetization factor N_{zz} (for the pre-
ferred direction z):
the internal may accentuate electromagnetic field loss
ferred direct that this is indeed the case is to examine Eqs. (4) and (5) in the limit of low but finite α_m . Four reduced relationships are found for μ' , μ'' , κ' , and κ'' :

$$
\mu' = 1 + \frac{\omega_{\rm m}\omega_0}{\omega_0^2 - \omega^2}
$$
 (15a)

$$
\mu'' = \frac{\omega_{\rm m}\omega\alpha_{\rm m}(\omega_0^2 + \omega^2)}{(\omega_0^2 - \omega^2)^2}
$$
\n(15b)

$$
\kappa' = -\frac{\omega_{\rm m}\omega}{\omega_0^2 - \omega^2} \tag{16a}
$$

$$
\kappa'' = -\frac{2\omega_0 \omega^2 \alpha_m \omega_m}{(\omega_0^2 - \omega^2)^2}
$$
 (16b)

These expressions are accurate to first order in α_{m} . As $\omega \rightarrow$ ω_0 , making the denominators in the loss component formulas

for u'' and κ'' approach zero, a second-order singularity is reached, namely $(\omega - \omega_0)^{-2}$, because

$$
\lim_{\omega \to \omega_0} \frac{1}{(\omega_0^2 - \omega^2)^2} = \lim_{\omega \to \omega_0} \frac{1}{(\omega_0 - \omega)^2 (\omega_0 + \omega)^2} = \frac{1}{2\omega(\omega_0 - \omega)^2}
$$
(17)

in the device. Nonreciprocal anisotropy is measured by the procity will quickly be lost. ratio of the real part of the diagonal permeability to the real part of the off-diagonal permeability, κ'/μ' . Invoking Eqs. (15a) and (16a),

$$
\frac{\kappa'}{\mu'} = -\frac{\omega_{\rm m}\omega}{\omega_0^2 - \omega^2 + \omega_{\rm m}\omega_0} \tag{18}
$$

For $\omega_0 \approx 0$, the formula approaches

$$
\lim_{\omega_0 \to 0} \frac{\kappa'}{\mu'} = \frac{\omega_m}{\omega} \tag{19}
$$

This formula implies that it is necessary to have a sizable $\omega_{\rm m}$ in order to obtain sizable circulation behavior, and this ω_m in order to obtain sizable circulation behavior, and this where relative values are used in the first formula and the means a large magnetization value. In addition, bandwidth of second defines the free space veloci means a large magnetization value. In addition, bandwidth of second defines the free space velocity of light. An X-band cir-
a well-designed circulator can be shown to be roughly equal culator is typically 4 mm to 5 mm in to ω_m , so there is a second reason for wanting large values of to ω_m , so there is a second reason for wanting large values of ter-wave devices are typically 1 mm or less, depending upon magnetization.

If $\omega \ll \omega$

$$
\lim_{\omega \ll \omega_0} \frac{\kappa'}{\mu'} = -\frac{\omega_m \omega}{\omega_0 (\omega_0 + \omega_m)}\tag{20}
$$

which further reduces if $\omega_m \ll \omega$

$$
\lim_{\omega, \omega_{\rm m} \ll \omega_0} \frac{\kappa'}{\mu'} = -\frac{\omega_{\rm m}\omega}{\omega_0^2} \tag{21}
$$

 $(\omega_0 \rightarrow \infty)$, we use, respectively, Eqs. (19) and (21) to find

$$
\lim_{\omega \to \infty, \omega_0 \to 0} \frac{\kappa'}{\mu'} = \lim_{\omega \to \infty} \frac{\omega_m}{\omega} = 0
$$
\n(22)

$$
\lim_{\omega \to \infty, \omega_0 \gg \omega} \frac{\kappa'}{\mu'} = -\lim_{\omega_0 \to \infty} \frac{\omega_m \omega}{\omega_0^2} = 0
$$
 (23)

The extreme limiting cases $\omega \rightarrow \infty$ and ω directly from Eq. (18). They tell us something about the actual tor with a nonideal geometrical configuration of the ferrite cases of ferrite material made out of yttrium iron garnet puck, permanent magnet, and flux return path. Even if the (YIG) or a hexagonal ferrite such as BaM or SrM (M stands applied magnetic field is maintained uniform, the internal for Fe₁₂O₁₉). For YIG, where Eq. (22) applies, it is noticed that magnetic field H_i , which determines the values of the eleno circulation behavior can be utilized at very high frequen- ments in the permeability tensor, will still not be uniform (excies. Therefore, for YIG, operation above the ferromagnetic cept in the extreme limit of infinitesimal substrate thickness). resonance is required, but not so high as to cause nonreciproc- Instead, the circulator's aspect ratio of radius to thickness ity to be lost. But the diameter of a circulator is constrained controls the degree to which the inhomogeneous demagnetizato be approximately half the wavelength λ_f in the ferrite me-

dium, because the puck acts (excluding the effects of the ports) as a distributed resonator; so this means that the operating resonance or electrical resonance must be above, but not too far above, the ferromagnetic resonance. Equation (23) applies to hexagonal material if the device is being operated far below the ferromagnetic resonance, and says that no circulation behavior will be found. Therefore, for BaM or SrM, op-This is precisely what makes it unacceptable to operate near eration below the ferromagnetic resonance is acceptable, but the ferromagnetic resonance frequency. The strength of the not so far below that nonreciprocity is the ferromagnetic resonance frequency. The strength of the not so far below that nonreciprocity is lost. Because ω_0 is fisingularity is first order in α_m . nite, on the order of 50 GHz, operation above the ferromag-Equations (15) and (16) may be used to assess the degree netic resonance is possible too, and here the applicable lim-
of circulation possible, which depends upon the amount of iting formula will be Eq. (22). Again, operat iting formula will be Eq. (22) . Again, operation too far above nonreciprocal anisotropy present in the ferrite material used this resonant point is not recommended, as useful nonreci-

> The wavelength λ_f in the ferrite medium is calculated using the effective two-dimensional permeability

$$
\frac{\kappa'}{\mu'} = -\frac{\omega_{\rm m}\omega}{\omega_0^2 - \omega^2 + \omega_{\rm m}\omega_0} \tag{18}
$$

 $\omega_0 \approx 0$, the formula approaches where the dependence on the ratio κ/μ is evident. From Eq. (24), the ferrite wavelength is calculated as

$$
\lambda_{\rm f} = \frac{c}{f} \frac{1}{\sqrt{\epsilon_{\rm f} \mu_{\rm eff}}}, \qquad c = \frac{1}{\sqrt{\epsilon_0 \mu_0}} \tag{25}
$$

the dielectric constant of the ferrite and the operating frequency. Examination of the impedance as a function of diameter shows that whereas microwave circulators will have values below 20 Ω , millimeter-wave devices can be designed to have values close to 50 Ω .

Static Internal Magnetic Field

In developing electromagnetic radio frequency (RF) field solutions for circulators, the simplest assumption for the dc bias magnetic field is that of a nonvarying or constant spatial field. In the limits of extremely high operating frequency ($\omega \to$ This may be satisfactory in many cases where the bias field ∞) or extremely high ferromagnetic resonance frequency circuit has been engineered to meet this requirement—
(∞ ∞) we use respectively Eqs. (19) and (21) to find particularly in the construction of permanent m dustrial applications, which is in a mature state of development, especially for low-frequency use. But this probably is not the case in hybrid or monolithic circuit applications for the microwave and millimeter-wave frequencies. Where laboratory measurements are conducted using large electromagnet pole pieces, the attainment of nearly constant magnetic field inside the pole pieces is assured. Such an arrangement is not possible, however, for a packaged miniaturized circulation field opposes the applied magnetic field.

One consequence of H_i variation is that the ferromagnetic in the previous \bm{B} expression, one finds the nonlinear Poisson resonance frequency, where the magnetic dissipation losses equation for the magnetostatic potential as in Newman and are a maximum, is spread out over a distribution of frequen- Krowne (3): cies. For ordinary circulators designed with the ferromagnetic resonance frequency well below the geometrical shield RF resonant frequency (which approximates the center frequency of the circulator operating band), cancellation of the applied bias Expanding this formula gives field by saturated magnetization leads to nearly zero H_i . Inhomogeneous demagnetization, however, can create a range of ferromagnetic resonance frequencies that are not zero and may become quite large close to the circulator perimeter, ^{or} where H_i can rise dramatically. Thus near the circulator perimeter, the ferromagnetic resonance may encroach on the low-frequency end of the operating bandwidth, bringing many problems, including large losses to the outermost annular
region. Any of the forms in Eqs. (31) to (33) may be solved for Ψ .
H, can be found by a direct self-consistent solution of May. The magnetostatic potential (an

well's magnetostatic (time-independent) equations, replacing tizing field) is conveniently solved in the cylindrical coordi-
the approximate demagnetization approach presented earlier atte system, consistent with a circula the approximate demagnetization approach presented earlier. nate system, consistent with a circular fer-
The relaxant equation is the curl \bf{H} relation. Ampere's law tion. Nonlinear Poisson Eq. (31) becomes The relevant equation is the curl H relation, Ampere's law governing the magnetic field H in a current free, time-independent environment:

$$
\nabla \times \boldsymbol{H} = 0 \tag{26}
$$

$$
\mathbf{H} = -\nabla \psi \tag{27}
$$

For nonlinear ferrite material, the constitutive relation is

$$
\mathbf{B} = \mu_{\rm f}(\mathbf{H} + \mathbf{M}) = \mu_0(\mathbf{H} + \mathbf{M}) \tag{28}
$$

in MKS units, where the second equality comes about from lem equation the near-equality of μ_f and μ_0 . In CGS units this relationship would have a factor 4π multiplying *M*. In either case, *M* is the magnetization inside the ferrite material caused by the ap plied field H , where we have dropped the earlier subscripts (*H*ap) for brevity. Note that the terms within parentheses are The magnitude of the gradient of the scalar magnetostatic the resulting internal field [see Eqs. (10) and (11)]. For ordi- potential Ψ in Eq. (36) is nary ferrites, the *B–H* relation can be assumed to be singlevalued because the hysteresis effect is small, and where it is most noticeable, near zero applied field, it is ignored. Such an assumption is not permissible for hexagonal ferrites, because they have a large anisotropy field (between 10,000 Oe and
30,000 Oe), which must be taken into account by Eq. (9), and
have very hysteretic $B-H$ curves.
In any event, working with ordinary ferrite materials, tained from t

where the single-valued nature of the *B*–*H* relationship is accepted, the magnetic flux density \bf{B} is a nonlinear, monotonically increasing function of H and in the same direction as *H*. The magnetization *M* is incorporated into a nonlinear per-
The puck volume is contained within the region $0 \le r \le$

$$
\boldsymbol{B} = \mu(H)\boldsymbol{H} \tag{29}
$$

$$
\nabla \cdot \boldsymbol{B} = 0 \tag{30}
$$

$$
\nabla \cdot [\mu(|\nabla \Psi|) \nabla \Psi] = 0 \tag{31}
$$

$$
\mu(|\nabla\Psi|)\nabla^2\Psi + \nabla\mu(|\nabla\Psi|)\cdot\nabla\Psi = 0 \qquad (32)
$$

$$
\nabla^2 \Psi + \frac{1}{\mu (|\nabla \Psi|)} \nabla \mu (|\nabla \Psi|) \cdot \nabla \Psi = 0 \tag{33}
$$

 H_i can be found by a direct self-consistent solution of Max-
il's magnetostatic (time-independent) equations replacing tizing field) is conveniently solved in the cylindrical coordi-

$$
\frac{1}{r}\frac{\partial}{\partial r}\left(r\mu(|\nabla\Psi|)\frac{\partial\Psi}{\partial r}\right) + \frac{1}{r}\frac{\partial}{\partial\phi}\left(\mu(|\nabla\Psi|)\frac{\partial\Psi}{\partial\phi}\right) + \frac{\partial}{\partial z}\left(\mu(|\nabla\Psi|)\frac{\partial\Psi}{\partial z}\right) = 0 \quad (34)
$$

Equation (26) is solved by specifying *H* as the gradient of a Because of the azimuthal (ϕ) symmetry, the three-dimen-
magnetostatic potential Ψ :
here Ψ is solved by specifying *H* as the gradient of a 2-D pr coordinates *r*, *z*:

$$
\frac{1}{r}\frac{\partial}{\partial r}\left(r\mu(|\nabla\Psi|)\frac{\partial\Psi}{\partial r}\right) + \frac{\partial}{\partial z}\left(\mu(|\nabla\Psi|)\frac{\partial\Psi}{\partial z}\right) = 0\tag{35}
$$

B B μ *M* μ *M*) μ *M* μ *M*) as a singularity at the origin, which is removable by multiplying through by *r*, giving the well-posed prob-

$$
\frac{\partial}{\partial r}\left(r\mu(|\nabla\Psi|)\frac{\partial\Psi}{\partial r}\right) + \frac{\partial}{\partial z}\left(r\mu(|\nabla\Psi|)\frac{\partial\Psi}{\partial z}\right) = 0 \tag{36}
$$

$$
|\nabla\Psi| = \left[\left(\frac{\partial \Psi}{\partial r} \right)^2 + \left(\frac{\partial \Psi}{\partial z} \right)^2 \right]^{1/2} \tag{37}
$$

$$
H_z = -\frac{\partial \Psi}{\partial z} \tag{38}
$$

meability factor $\mu(H)$, where *H* is the field magnitude, yield-
ing
ing
reduces the 3-D problem to one of two dimensions, and sym-
reduces the 3-D problem to one of two dimensions, and symmetry further simplifies it to the rectangular domain $0 \le r \le L_r$, and $0 \le z \le L_z$. In the final reduced domain, the ferrite material occupies the region $0 \le r \le a$ and $0 \le z \le h$. The Since the divergence of \bm{B} is zero, problem is solved for the case when an external magnetic field $H_{av} = H_{av} \hat{z}$ is applied; that is, when the puck is removed, only a uniform field exists in the *z* direction. Therefore, we

of the magnetostatic potential Ψ normal to the boundary only ferrite and external dielectric regions. be in the *z* direction and have a value

$$
\frac{\partial \Psi}{\partial z} = -H_{\rm ap}, \qquad z = L_z \text{ and } 0 \le r \le L_r \tag{39}
$$

At the center of the puck, due to symmetry (midline $r = 0$, $0 \leq z \leq L_z$), and on the outside circumference $(r = L_r, 0 \leq$ $z \leq L_z$) of the puck and far from it, the magnetostatic potential normal to the boundary has zero value (zero *r*-directed field), so that (45)
field), so that

$$
\frac{\partial \Psi}{\partial r} = 0, \qquad r = 0 \text{ and } 0 \le z \le L_z \tag{40}
$$

$$
\frac{\partial \Psi}{\partial r} = 0, \qquad r = L_r \text{ and } 0 \le z \le L_z \tag{41}
$$

of the magnetostatic potential Ψ parallel to the boundary response point located at ϕ when specializing to the perimeter $(z = 0, 0 \le r \le L_r)$ must be zero due to symmetry (zero *r*- $r = R$. Equation (45) on the right-hand side for G_{un} is given directed field):
in abbreviated notation, and hides the fact that this Green's

$$
\frac{\partial \Psi}{\partial r} = 0, \qquad z = 0, \quad 0 \le r \le L_r \tag{42}
$$

$$
\Psi = \text{constant}, \qquad z = 0, \quad 0 \le r \le L_r \tag{43}
$$

to zero.

The permeability function $\mu(H)$ is constructed as follows. Outside the puck, $\mu(H) = \mu_0$. Inside the puck, it is required that the permeability function be single-valued, necessitating neglect of hysteresis. A reasonable and convenient analytical approximation developed for $\mu(H)$ is given in Newman and Krowne (3) as This may be put into a much more compact form if the prod-

$$
\mu(H) = \mu_0 \left(1 + \frac{M_s}{\sqrt{H_1^2 + H^2}} \right) \tag{44}
$$

 M_s is the saturation magnetization, and $H₁$ is the corner magnetic field, at which the magnetization reaches 0.707 times its saturation value. The corner field H_1 is often on the order of 1 Oe, and at that field the magnetic flux density \vec{B} is on One obtains from Eq. (47), using Eq. (48), the order of but still much less than the saturation magnetization, which is often on the order of thousands of gauss. An advantage of the ferrite model (44) over a piecewise linear model is that it is continuous, producing continuous Jacobian matrix elements that can be calculated explicitly in a numeri- **Two-Dimensional Soft Wall Case** cal procedure. If it is desired to find some way of determining the effect of

the puck (see Fig. 1), and this leads to what is referred to as of changes in the permittivity ϵ_d and permeability μ_d on circuthe uniform Green's function solution. Uniform Green's func- lator performance. The three common cases of air as the extion solution is found assuming that perfect magnetic walls ternal medium, a dielectric as the external medium, and an for arcs connecting port apertures. That case may also be re- unmagnetized ferrite as the external medium are all easy to ferred to as the *hard wall* case, since electromagnetic waves treat with the soft wall dyadic Green ferred to as the *hard wall* case, since electromagnetic waves

require, far from the puck (say at $z = L_z$), that the gradient cannot propagate through the interfacial arcs separating the

Two-Dimensional Hard Wall Case

The uniform 2-D Green's function for the hard wall situation is

$$
G_{\rm un}(\phi, \phi_{\rm q}) = \frac{i\zeta_{\rm eff}}{2\pi} \sum_{n=-\infty}^{\infty} \frac{J_n(k_{\rm eff}r)}{J'_n(k_{\rm eff}r) - \frac{\kappa}{\mu} \frac{n}{k_{\rm eff}r} J_n(k_{\rm eff}r)} e^{in(\phi - \phi_{\rm q})}
$$
(45)

where the effective impedance coefficient is given by

$$
\frac{\partial r}{\partial \Psi} = 0 \qquad r = I \quad \text{and} \quad 0 \le z \le I \tag{41}
$$

This is precisely Bosma's (1) uniform Green's function solu-Finally, at the midplane ($r\phi$ plane) of the puck, the gradient tion relating one angular source point located at ϕ_n to the in abbreviated notation, and hides the fact that this Green's function does not have to be specialized to the contour circulator perimeter (where $r = R$) and that it only relates the driving magnetic field source *H* to the resulting electric field *E*. Integration of Eq. (40) yields Furthermore, it only relates an azimuthal magnetic field re-
Source (ϕ component) to a perpendicular electric field response (*z* component). So in reality, Eq. (45) represents only one dyadic element of a complete dyadic Green's function. and because of superposition and the gradient nature of the Froperly stated in explicit general form, the uniform Green's magnetic field, this constant is arbitrary and so may be set

$$
G_{EH,un}^{z\phi}(r,\phi;R,\phi_{q})
$$

=
$$
\frac{i\zeta_{\text{eff}}}{2\pi} \sum_{n=-\infty}^{\infty} \frac{J_{n}(k_{\text{eff}}r)}{J'_{n}(k_{\text{eff}}r) - \frac{\kappa}{\mu} \frac{n}{k_{\text{eff}}r} J_{n}(k_{\text{eff}}r)}
$$
 $e^{in(\phi-\phi_{q})}$ (47)

uct of part of the summation prefactor and the radial part of the summand is defined as

$$
\overline{\gamma}_{n0}^{z\phi} = i\zeta_{\text{eff}} \frac{J_n(k_{\text{eff}}r)}{J'_n(k_{\text{eff}}r) - \frac{\kappa}{\mu} \frac{n}{k_{\text{eff}}r} J_n(k_{\text{eff}}r)}
$$
(48)

$$
G_{EH,un}^{z\phi}(r,\phi;R,\phi_{q}) = \frac{1}{2\pi} \sum_{n=-\infty}^{\infty} \overline{\gamma}_{n0}^{z\phi} e^{in(\phi-\phi_{q})}
$$
(49)

the external dielectric region on the circulator behavior, the **UNIFORM TWO-DIMENSIONAL GREEN'S FUNCTION** perfect magnetic walls must be replaced by penetrable walls. A dyadic Green's function allowing for such *soft wall* (as op-Simplest case to treat is that of a uniform ferrite material in posed to hard wall) conditions enables us to find out the effect

Applying the radiation condition as $r \to \infty$ leads to the se- For $r > R$ (outside the circulator puck), the dyadic Green's lection of the modified Bessel function of the second kind, function elements are $K_n(k_d r)$, for use in the external field construction, $r > R$. It is assumed that the same field modes are maintained in the device for radii exceeding the circulator radius, so that a consistent 2-D modeling procedure holds inside and outside the device. Additionally, the contribution of the microstrip edge effect and fringing field provides the correct field available from the circulator puck for coupling to the external environment when multiplied by the factor *f*. How to find *f* is discussed in Krowne (4). With these constraints, the internal TM, nature of the field persists for $r > R$, whence

$$
E_z^d = \sum_{n=-\infty}^{\infty} a_{ne}^d K_n (k_d r) e^{in\phi}
$$
 (50)

$$
H_{\phi}^{\rm d} = \frac{1}{i\omega\mu_{\rm d}} \sum_{n=-\infty}^{\infty} a_{n\rm e}^{\rm d} k_{\rm d} K_n'(k_{\rm d}r) e^{in\phi} \tag{51}
$$

Continuity of the perpendicular electric field at $r = R$ is required:

$$
fE_z^{\rm c}(R,\phi) = E_z^{\rm d}(R,\phi) \tag{52}
$$

This gives

$$
a_{ne}^{d} = f \frac{J_n(k_e R)}{K_n(k_d R)} a_{n0}
$$
 (53)

$$
k_{\rm d} = \omega \sqrt{\epsilon_{\rm d} \mu_{\rm d}} \eqno{(54)}
$$

 $(r', \phi'), r = R$, through the equality

$$
H_{\phi}^{\text{Per}}(R,\phi)=H_{\phi'\mathbf{A}}\delta(\phi-\phi')\,\Delta\phi'+H_{\phi}^{\text{d}}(R,\,\phi\neq\phi')\qquad \quad (55)
$$

Obtaining solution of internal puck amplitude coefficient a_{n0} Assign $A = \pi R^2$ and $W = 2\pi R$, and place them in Eq. (62) and in terms of the forcing field $H_{\phi A}$, the elements of the dyadic in the equivalent expression for the additional radial length Green's function for $r < R$ (within the circulator puck) may Δl_f , which relates to the fringing capacitance C_f : be written as

$$
G_{EH}^{z\phi}(r,\phi;R,\phi') = \frac{i\omega}{2\pi} \sum_{n=-\infty}^{\infty}
$$

$$
\frac{J_n(k_e r)e^{in(\phi-\phi')}}{\frac{1}{\mu_e} \left(k_e J'_n(k_e R) - \frac{n\kappa}{\mu} \frac{1}{R} J_n(k_e R) \right) - f \frac{k_d}{\mu_d} \frac{J_n(k_e R)}{K_n(k_d R)} K'_n(k_d R)}
$$
(56)

$$
G_{HH}^{\phi\phi}(r,\phi;R,\phi') = \frac{1}{2\pi} \sum_{n=-\infty}^{\infty}
$$

$$
\frac{\left(J'_{n}(k_{e}r) - \frac{n\kappa}{\mu}\frac{1}{k_{e}r}J_{n}(k_{e}r)\right)e^{in(\phi-\phi')}}{J'_{n}(k_{e}R) - \frac{n\kappa}{\mu}\frac{1}{k_{e}R}J_{n}(k_{e}R) - f\frac{\mu_{e}}{\mu_{d}}\frac{k_{d}}{k_{e}}\frac{J_{n}(k_{e}R)}{K_{n}(k_{d}R)}K'_{n}(k_{d}R)}
$$
(57)

$$
G_{HH}^{\phi}(r, \phi; R, \phi') = \frac{i}{2\pi} \sum_{n = -\infty}^{\infty} \left(\frac{n}{k_{\rm e}r} J_n(k_{\rm e}r) - \frac{\kappa}{\mu} J'_n(k_{\rm e}r) \right) e^{in(\phi - \phi')}
$$

$$
J'_n(k_{\rm e}R) - \frac{n\kappa}{\mu} \frac{1}{k_{\rm e}R} J_n(k_{\rm e}R) - f \frac{\mu_{\rm e}}{\mu_{\rm d}} \frac{k_{\rm d}}{k_{\rm e}} \frac{J_n(k_{\rm e}R)}{K_n(k_{\rm d}R)} K'_n(k_{\rm d}R)
$$
(58)

 ∞

NUMERICAL MODELING OF CIRCULATORS 7

$$
G_{EH}^{z\phi}(r,\phi;R,\phi') = \frac{i\omega f}{2\pi} \sum_{n=-\infty}^{\infty}
$$

$$
\frac{J_n(k_eR)}{K_n(k_dR)} K_n(k_d r) e^{in(\phi-\phi')}
$$

$$
\frac{1}{\mu_e} \left(k_e J'_n(k_eR) - \frac{n\kappa}{\mu} \frac{1}{R} J_n(k_eR) \right) - f \frac{k_d}{\mu_d} \frac{J_n(k_eR)}{K_n(k_dR)} K'_n(k_dR)
$$
(59)

$$
G_{HH}^{\phi\phi}(r, \phi; R, \phi') = \frac{\mu_{e}}{\mu_{d}} \frac{k_{d}}{k_{e}} f \frac{1}{2\pi} \sum_{n=-\infty}^{\infty} \n\frac{J_{n}(k_{e}R)}{K_{n}(k_{d}R)} K'_{n}(k_{d}r) e^{in(\phi-\phi')}
$$
\n
$$
\frac{J_{n}(k_{e}R)}{J'_{n}(k_{e}R)} - \frac{n\kappa}{\mu} \frac{1}{k_{e}R} J_{n}(k_{e}R) - f \frac{\mu_{e}}{\mu_{d}} \frac{k_{d}}{k_{e}} \frac{J_{n}(k_{e}R)}{K_{n}(k_{d}R)} K'_{n}(k_{d}R)
$$
\n(60)

$$
G_{HH}^{\rho} (r, \phi; R, \phi') = -n \frac{\mu_e}{\mu_d} k_e \frac{f}{r} \frac{i}{2\pi} \sum_{n = -\infty}^{\infty} \frac{J_n(k_e R)}{K_n(k_d R)} K_n(k_d r) e^{in(\phi - \phi')}
$$
\n
$$
J'_n(k_e R) - \frac{n\kappa}{\mu} \frac{1}{k_e R} J_n(k_e R) - f \frac{\mu_e}{\mu_d} \frac{k_d}{k_e} \frac{J_n(k_e R)}{K_n(k_d R)} K'_n(k_d R)
$$
\n(61)

where **The factor** *f* is estimated as $f = f_w f_p$, where f_w weights the parameter dependence expression in f_p . Closed-form for*k* mulas, based upon self-consistent static solutions, exist for *f* attempts in an approximate way to allow for consistent microstrip capacitive (electric) end effects. Stretching the fininging in the 2-D model, which has some inherent degree of 3-D nature.
3-D nature.
The forcing fun

$$
f_{\rm p} = \frac{C_{\rm T} - C}{C} = \frac{C_{\rm f}}{C} = \frac{h}{A \epsilon_{\rm d}} C_{\rm f}
$$
(62)

$$
\frac{\Delta l_{\rm f}}{h} = \frac{C_{\rm f}}{W} \frac{cZ_{\rm m}W/h}{\sqrt{\epsilon_{\rm rde}}} \tag{63}
$$

where c is the speed of light in vacuum, h the substrate thickness, $Z_{\rm m}$ the microstrip impedance based on dielectric $\epsilon_{\rm d}$ loading causing an effective dielectric constant ϵ_{de} , and the subscript r denotes relative value. We replace ϵ_{de} by ϵ_{d} in the limit $W/h \ge 1$. The left-hand side of Eq. (63) is given by

$$
\frac{\Delta l_{\rm f}}{h} = 0.412 \frac{\epsilon_{\rm rde} + 0.300 \, W/h + 0.264}{\epsilon_{\rm rde} - 0.258 \, W/h + 0.800} \tag{64}
$$

Using Eqs. (63) and (64) in Eq. (62) , the final formula for f is

$$
f_{\rm p} = \frac{0.824h}{R\sqrt{\epsilon_{\rm rd}}} \frac{\epsilon_{\rm rd} + 0.300 R/h + 0.042}{\epsilon_{\rm rd} - 0.258 R/h + 0.127} \times \left\{ 1 + \frac{h}{R} \left[0.2217 + 0.106 \ln \left(2\pi \frac{R}{h} + 1.444 \right) \right] \right\}
$$
(65)

We have assumed that the cover location $h' \ge h$ in deriving Eq. (65).

as a dependence on the azimuthal mode index *n*. The prefac- wall dyadic Green's function to be found. tor f_w may be very complicated, and the best that one can do is to obtain some reasonable degree of approximation. **Three-Dimensional Uniform Soft Wall Case**

treatment is that inclusion of finite puck thickness creates a perpendicular propagation constant k_z , and its existence so that an explicit dyadic Green's function solution can be makes the radial propagation constant split into two dissimi- sought. Fields external to the puck in the dielectric region lar values. Perfect magnetic walls are still maintained, how- look like ever, on those segments of the circulator perimeter where ports do not exist. Electromagnetic fields now have variation in the perpendicular coordinate direction *z*. As a consequence, the field solution for the circulator is considerably complicated. Figure 1 still applies to a $z = \text{const}$ plane cut through H_z^d

Three-Dimensional Uniform Hard Wall Case

its most extreme position $r = R$ is expressed using Krowne (5) as $\sigma_{d j} = \sqrt{k_d^2 - k_{z j}^2}$, $k_d =$

$$
E_z^c = \sum_{j=0}^{\infty} \sum_{n=-\infty}^{\infty} \cos(k_{zj}z) \left[a_{n0j}^1 J_n(\sigma_{1j}R) + a_{n0j}^2 J_n(\sigma_{2j}R)\right] e^{in\phi} \tag{66}
$$

The perpendicular magnetic field in the circulator, as $r \to R$ *k*_{zj} = $\frac{j\pi}{h}$

$$
H_z^c = \sum_{j=1}^{\infty} \sum_{n=-\infty}^{\infty} i \sin(k_{zj}z) \left(a_{n0j}^1 \frac{c_j - \lambda_{2j}}{b_j} J_n(\sigma_{1j}R) + a_{n0j}^2 \frac{c_j - \lambda_{1j}}{b_j} J_n(\sigma_{2j}R) \right) e^{in\phi}
$$
\n(67)

The circulator field E_{ϕ}^c at its most extreme position $r = R$ is expressed as tors $\partial/\partial r$ and $\partial/\partial \phi$ equal to zero:

$$
E_{\phi}^{\rm c} = \sum_{j=1}^{\infty} \sum_{n=-\infty}^{\infty} i \sin(k_{zj}z)
$$

\n
$$
\times \left[a_{n0j}^1 \left(\frac{-in\overline{r}_j}{b_jR} \lambda_{2j} J_n(\sigma_{1j}R) + \frac{\sigma_{1j}}{b_j} (i\omega\mu_0 + s_j \lambda_{2j}) J'_n(\sigma_{1j}R) \right) + a_{n0j}^2 \left(\frac{-in\overline{r}_j}{b_jR} \lambda_{1j} J_n(\sigma_{2j}R) + \frac{\sigma_{2j}}{b_j} (i\omega\mu_0 + s_j \lambda_{1j}) J'_n(\sigma_{2j}R) \right) \right] e^{in\phi}
$$
(68)

$$
H_{\phi}^{c} = \sum_{j=0}^{\infty} \sum_{n=-\infty}^{\infty} \cos(k_{zj}z) \left\{ a_{n0j}^{1} \left[\frac{in}{b_{j}R} \left(ik_{z} \frac{\mu_{0}}{\mu} - p_{j} \lambda_{2j} \right) J_{n}(\sigma_{1j}R) \right. \right.\left. + \frac{q_{j}}{b_{j}} \lambda_{2j} \sigma_{1j} J'_{n}(\sigma_{1j}R) \right] + a_{n0j}^{2} \left[\frac{in}{b_{j}R} \left(ik_{z} \frac{\mu_{0}}{\mu} - p_{j} \lambda_{1j} \right) \right. \quad (69) \quad \text{w}
$$

$$
\times J_{n}(\sigma_{2j}R) + \frac{q_{j}}{b_{j}} \lambda_{1j} \sigma_{2j} J'_{n}(\sigma_{2j}R) \right] \left\{ e^{in\phi} \right\}
$$

One would expect the prefactor f_w to contain information Working with the fields given by Eqs. (66) to (69) (replace *R* on the azimuthal mode structure, and this will be displayed by *r* for the dependence within the puck) enables the hard

UNIFORM THREE-DIMENSIONAL GREEN'S FUNCTION With the assumption that the electric wall conditions are approximately maintained for radii exceeding the circulator ra-The big difference between the 2-D treatment and the 3-D dius, so that the same *z*-indexing modal set can be used inside treatment is that inclusion of finite puck thickness creates a and outside the device, the problem b

$$
E_z^{\mathrm{d}}(r,\phi,z) = \sum_{j=0}^{\infty} \sum_{n=-\infty}^{\infty} a_{n\epsilon j}^{\mathrm{d}} \cos(k_{zj}z) K_n(\sigma_{\mathrm{d}j}r) e^{in\phi}
$$
 (70)

$$
H_z^{\mathrm{d}}(r,\phi,z) = \sum_{j=1}^{\infty} \sum_{n=-\infty}^{\infty} i a_{n\dot{n}j}^{\mathrm{d}} \sin(k_{zj}z) K_n(\sigma_{\mathrm{d}j}r) e^{in\phi} \qquad (71)
$$

The transverse electromagnetic field components within the
circulator can be expressed in terms of the perpendicular election of the perpendicular electric and magnetic field components. The circulator field E_z^e at sin

$$
\sigma_{\rm d j} = \sqrt{k_{\rm d}^2 - k_{\rm zj}^2}, \qquad k_{\rm d} = \omega \sqrt{\epsilon_{\rm d} \mu_{\rm d}} \tag{72}
$$

where the perpendicular indexing for the discrete spectrum of allowed values is done according to

$$
k_{zj} = \frac{j\pi}{h}, \qquad j = (0 \text{ or } 1), 2, \dots \tag{73}
$$

with the first *j* index choice determined by the first nontrivial field component.

The azimuthal magnetic field component H^{d}_{ϕ} (only the transverse part) may be made to retain a form congruent with the puck field construction, following Krowne (6), by setting the coefficient factors q and t of the partial differential opera-

$$
H_{\phi}^{\rm d} = \frac{p}{r} \frac{\partial H_z^{\rm d}}{\partial \phi} - u \frac{\partial E_z^{\rm d}}{\partial r}
$$
 (74)

with

$$
p = \frac{i k_{zj}}{k_{\rm d}^2 - k_{zj}^2}, \qquad u = \frac{i \omega \epsilon_{\rm d}}{k_{\rm d}^2 - k_{zj}^2} \tag{75}
$$

Similarly, the azimuthal electric field component $E_{\phi}^{\textrm{d}}$ (only the transverse part) may be made to retain a form congruent with An azimuthal magnetic field in the circulator, as $r \to R$ from
the puck field construction by setting the coefficient factors \overline{r} and q of the partial differential operators $\partial/\partial \phi$ and $\partial/\partial r$ equal
to zero:

$$
E_{\phi}^{\rm d} = -s\frac{\partial H_z^{\rm d}}{\partial r} + \frac{p}{r}\frac{\partial E_z^{\rm d}}{\partial \phi} \tag{76}
$$

with

$$
s = -\frac{i\omega\mu_{\rm d}}{k_{\rm d}^2 - k_{zj}^2} \tag{77}
$$

The perpendicular magnetic field forcing function for the Green's function is applied at (r', ϕ') , $r = R$, through the equality

$$
H_z^{\text{Per}}(R,\phi) = H_{zA}h(z)\delta(\phi - \phi')\,\Delta\phi' + H_z^{\text{d}}(R,\,\phi \neq \phi')\tag{78}
$$

Here $h(z)$ is the functional behavior of the forcing perpendicular magnetic field in the *z* direction. This relationship must be added to that in Eq. (55) to completely describe the source. Using the puck field forms given by Eqs. (66) to (69) and the external-region fields given by Eqs. (70), (71), (74), and (76) enables the soft wall dyadic Green's function to be found.

puck has varying properties throughout its radial extent (see require a magnetic wall as shown. Soft wall conditions necessitate its Fig. 2). Its magnetization, demagnetization factor, and applied magnetization factor is t radius. The Green's functions utilize recursive relationships between adjacent radial sections or rings to provide compact expressions, the actual algebraic factors contained inside the If we assign a notation similar to that found in Eq. (82) to summations being extremely complicated. the radial numerator factors in Eqs. (79) to (81),

Two-Dimensional Inhomogeneous Hard Wall Case *γ*

The dyadic Green's function elements are now given by the γ new expressions provided in Krowne (7):

$$
G_{EHi}^{z\phi}(r,\phi;R,\phi_{k}^{q}) = \frac{1}{2\pi} \sum_{n=-\infty}^{\infty} \n\frac{a_{ni}(\text{recur})C_{neai}(r) + b_{ni}(\text{recur})C_{nebi}(r)}{\gamma_{nN}} e^{-in\phi_{k}^{q}} e^{in\phi} \quad (79)
$$
\n
$$
G_{HHi}^{\phi\phi}(r,\phi;R,\phi_{k}^{q}) = \frac{1}{2\pi} \sum_{n=-\infty}^{\infty}
$$

$$
\frac{a_{ni}(\text{recur})C_{nchi}^{\phi}(r) + b_{ni}(\text{recur})C_{nhh}^{\phi}(r)}{\gamma_{nN}} e^{-in\phi_{k}^{q}} e^{in\phi}
$$
 (80)

$$
G_{HHi}^{r\phi}(r,\phi;R,\phi_{k}^{q}) = \frac{1}{2\pi} \sum_{n=-\infty}^{\infty} \frac{a_{ni}(\text{recur})C_{nhai}'(r) + b_{ni}(\text{recur})C_{nhbi}'(r)}{\gamma_{nN}} e^{-in\phi_{k}^{q}} e^{in\phi}
$$
 (81)

where

$$
\gamma_{nN} = \gamma_{nN}^{\phi h} = a_{nN}(\text{recur})C_{nhaN}^{\phi}(R) + b_{nN}(\text{recur})C_{nhbN}^{\phi}(R) \quad (82)
$$

tion element differs based on the numerator sum character each port *k*. One can see from this discussion that the final inside the infinite summation changing from one element to form of the $z\phi$ element is precisely the same as for the unianother. The sum in each numerator is constructed from re- form case in Eq. (49). This is no coincidence. Compacting the cursion coefficients a_{ni} (recur) and b_{ni} (recur), which give the recursion process and the separable property of the partial correct coefficient in the *i*th ring after successive recursion differential equation describing electromagnetic waves within processes have been performed on all previous annuli within the circulator enables the inhomogeneous problem solution to the ferrite puck. be developed in this manner.

INHOMOGENEOUS TWO-DIMENSIONAL Figure 2. Top view (as in Fig. 1) of an inhomogeneous circulator. **DYADIC GREEN'S FUNCTION** Within the perimeter is ferrite with radially varying parameters, broken up into *N* annuli, each uniform. Outside the perimeter are the A new aspect of the inhomogeneous case is that the circulator ports (three here) and the external dielectric. Hard wall conditions nucle has varying properties throughout its radial extent (see require a magnetic wall as s

$$
r_{ni}^{ze}(r) = a_{ni}(\text{recur})C_{nhai}^z(r) + b_{ni}(\text{recur})C_{nhbi}^z(r) \tag{83}
$$

$$
r_{ni}^{\phi h}(r) = a_{ni}(\text{recur})C_{nhai}^{\phi}(r) + b_{ni}(\text{recur})C_{n hbi}^{\phi}(r) \qquad (84)
$$

$$
r_{ni}^{rh}(r) = a_{ni}(\text{recur})C_{nhai}^r(r) + b_{ni}(\text{recur})C_{n hbi}^r(r) \qquad (85)
$$

^G and define normalized quantities *^z*^φ

 γ

$$
\overline{\gamma}_{ni}^{pq}(r) = \frac{\gamma_{ni}^{pq}(r)}{\gamma_{n}^{ph}(R)}\tag{86}
$$

then the dyadic Green's function elements given in Eqs. (79) to (81) can be streamlined. Here $p = z$, ϕ , r and $q = e$, h .

Final compacted forms for the 2-D hard wall dyadic Green's function elements are

$$
G_{EHi}^{z\phi}(r,\phi;R,\phi_k^q) = \frac{1}{2\pi} \sum_{n=-\infty}^{\infty} \overline{\gamma}_{ni}^{ze}(r) e^{in(\phi-\phi_k^q)} \tag{87}
$$

$$
G_{HHi}^{\phi\phi}(r,\phi;R,\phi_k^q) = \frac{1}{2\pi} \sum_{n=-\infty}^{\infty} \overline{\gamma}_{ni}^{\phi h}(r) e^{in(\phi-\phi_k^q)}
$$
(88)

$$
G_{HHi}^{r\phi}(r,\phi;R,\phi_k^q) = \frac{1}{2\pi} \sum_{n=-\infty}^{\infty} \overline{\gamma}_{ni}^{rh}(r) e^{in(\phi-\phi_k^q)}
$$
(89)

The indexing of the azimuthal angle ϕ has to do with identi-Notice that the radial variation of each dyadic Green's func- fying the location of the port *q* and the discretization within

Two-Dimensional Inhomogeneous Soft Wall Case INHOMOGENEOUS THREE-DIMENSIONAL

Like the hard wall case, inhomogeneity complicates the elec-
 DYADIC GREEN'S FUNCTION tromagnetic problem, but with the techniques of compacting
the dimensions tremendously changes the level of analysis
the recursion process, the dyadic Green's function elements
required and in addition gives us the full co

$$
G_{EHi}^{z\phi}(r, \phi; R, \phi') = \frac{1}{2\pi} \sum_{n=-\infty}^{\infty} \frac{a_{ni}(\text{recur})C_{neai}(r) + b_{ni}(\text{recur})C_{nebi}(r)}{\gamma_{nN} - \frac{fk_d}{i\omega\mu_d} \frac{\gamma_{nN}^{z\phi}}{K_n(k_dR)} K'_n(k_dR)}
$$
(90)

$$
G_{HHi}^{\phi} (r, \phi; R, \phi') = \frac{1}{2\pi} \sum_{n=-\infty}^{\infty} \frac{a_{ni}(\text{recur}) C_{nhai}^{\phi}(r) + b_{ni}(\text{recur}) C_{nhbi}^{\phi}(r)}{\gamma_{nN} - \frac{fk_d}{i\omega\mu_d} \frac{\gamma_{nN}^{ze}}{K_n(k_dR)} K'_n(k_dR)}
$$
(91)

 $G_{HHi}^{r\phi}(r, \phi; R, \phi')$

$$
= \frac{1}{2\pi} \sum_{n=-\infty}^{\infty} \frac{a_{ni}(\text{recur})C_{nhai}^r(r) + b_{ni}(\text{recur})C_{nhbi}^r(r)}{\gamma_{nN} - \frac{fk_d}{i\omega\mu_d} \frac{\gamma_{nN}^{ze}}{K_n(k_dR)} K_n'(k_dR)}
$$
(92)

It is evident comparing Eqs. (90) to (92) with Eqs. (79) to (81) that the new dyadic Green's function elements are those of a circulator device with hard walls (namely magnetic walls), but with a modification to the form of the denominator. This modification is in the form of a subtraction from the original circulator divisor γ_{N} , and depends on the properties of the external medium, on the internal circulator field behavior through γ_{nN}^{ze} , and on the factor *f*.

The elements of the dyadic Green's function external to the circulator, in the nonport regions, are

$$
G_{EHd}^{z\phi}(r, \phi; R, \phi') = \frac{1}{2\pi} \sum_{n=-\infty}^{\infty} \frac{f\gamma_{nN}^{ze}}{K_n(k_dR)} \frac{K_n(k_d r)}{\gamma_{nN} - \frac{fk_d}{i\omega\mu_d} \frac{\gamma_{nN}^{ze}}{K_n(k_dR)} K'_n(k_dR)} e^{in(\phi - \phi')} \tag{93}
$$

$$
G_{HHd}^{\phi\phi}(r,\phi;R,\phi') = \frac{1}{2\pi} \sum_{n=-\infty}^{\infty} \frac{fk_{\rm d}}{i\omega\mu_{\rm d}K_n(k_{\rm d}R)} \frac{\gamma_{n\rm N}^{ze}}{\gamma_{n\rm N} - \frac{fk_{\rm d}}{i\omega\mu_{\rm d}}\frac{\gamma_{n\rm N}^{ze}}{K_n(k_{\rm d}R)}K'_n(k_{\rm d}R)} e^{in(\phi-\phi')}
$$
\n(94)

$$
G_{HHd}^{r\phi}(r, \phi; R, \phi') = \frac{1}{2\pi} \sum_{n=-\infty}^{\infty} \frac{-n f}{\omega \mu_{d}} \frac{\gamma_{nN}^{ze}}{K_{n}(k_{d}R)} \frac{K_{n}(k_{d}r)}{\gamma_{nN} - \frac{f k_{d}}{i\omega \mu_{d}} \frac{\gamma_{nN}^{ze}}{K_{n}(k_{d}R)} K_{n}'(k_{d}R)} e^{in(\phi - \phi')}
$$
\n(95)

These $r > R$ dyadic Green's function elements are completely new and not only contain the denominator correction term but also functional forms that assure that any fields constructed from them will decay properly outside the device.

field components and three magnetic field components. Because of the nature of the source vector function generating the Green's function, there will be twelve individual dyadic Green's function elements. Two infinite summations are employed in creating each element: the double-sided summation on the azimuthal index *n*, which we saw before, and the added (90) singled-sided perpendicular summation. The azimuthal summation is retained as the inner summation, and the perpendicular summation added as the outer summation.

Three-Dimensional Inhomogeneous Hard Wall Case

The perpendicular summation is expected to be very small, requiring only a few terms for normally thin circulators. Only those devices prepared in a more bulk, large-scale, waveguide format will need extra terms. Clearly, circulator substrate thicknesses small compared to the wavelength in ferrite will use only one term, because only the lowest-order perpendicular mode will satisfy the bottom ground plane and upper mi-(92) crostrip shield boundary conditions. Referring to Krowne (8),

$$
G_{EHi}^{z\phi} = \frac{1}{2\pi} \sum_{j=0}^{\infty} \sum_{n=-\infty}^{\infty} K_{zj+} \cos(k_{zij+}z) \frac{1}{D_{ABj}}
$$

× $[B_{nj}^2 T_{neji}^{z1}(r) - B_{nj}^1 T_{neji}^{z2}(r)]e^{-in\phi_{k}^q}e^{in\phi}$ (96)

$$
G_{EHi}^{zz} = \frac{1}{2\pi} \sum_{j=0}^{\infty} \sum_{n=-\infty}^{\infty} K_{zj+} \cos(k_{zij+}z) \frac{1}{D_{ABj}}
$$

× $[A_{nj}^1 T_{neji}^{z2}(r) - A_{nj}^2 T_{neji}^{z1}(r)]e^{-in\phi_{k}^q}e^{in\phi}$ (97)

$$
G_{EHi}^{\phi\phi} = \frac{1}{2\pi} \sum_{j=0}^{\infty} \sum_{n=-\infty}^{\infty} i K_{zj+} \sin(k_{zij+}z) \frac{1}{D_{ABj}}
$$

× $[B_{nj}^2 T_{neji}^{\phi 1}(r) - B_{nj}^1 T_{neji}^{\phi 2}(r)]e^{-in\phi_{k}^q}e^{in\phi}$ (98)

$$
G_{EHi}^{\phi z} = \frac{1}{2\pi} \sum_{j=0}^{\infty} \sum_{n=-\infty}^{\infty} i K_{zj+} \sin(k_{zij+} z) \frac{1}{D_{ABj}}
$$

× $[A_{nj}^1 T_{neji}^{\phi 2}(r) - A_{nj}^2 T_{neji}^{\phi 1}(r)]e^{-in\phi_k^q}e^{in\phi}$ (99)

$$
G_{EHi}^{r\phi} = \frac{1}{2\pi} \sum_{j=0}^{\infty} \sum_{n=-\infty}^{\infty} i K_{zj+} \sin(k_{zij+}z) \frac{1}{D_{ABj}}
$$

× $[B_{nj}^2 T_{neji}^{r1}(r) - B_{nj}^1 T_{neji}^{r2}(r)]e^{-in\phi_{k}^q}e^{in\phi}$ (100)

$$
G_{EHi}^{r\phi} = \frac{1}{2\pi} \sum_{j=0}^{\infty} \sum_{n=-\infty}^{\infty} iK_{zj+} \sin(k_{zij+}z) \frac{1}{D_{ABj}}
$$
(101)

$$
G_{EHi}^{r\phi} = \frac{1}{2\pi} \sum_{j=0}^{\infty} \sum_{n=-\infty}^{\infty} iK_{zj+} \sin(k_{zij+}z) \frac{1}{D_{ABj}}
$$
(101)

$$
G_{HHi}^{z\phi} = \frac{1}{2\pi} \sum_{j=0}^{\infty} \sum_{n=-\infty}^{\infty} i K_{zj+} \sin(k_{zij+} z) \frac{1}{D_{ABj}}
$$

× $[B_{nj}^2 T_{nhji}^{z1}(r) - B_{nj}^1 T_{nhji}^{z2}(r)]e^{-in\phi_k^q}e^{in\phi}$ (102)

$$
G_{HHi}^{zz} = \frac{1}{2\pi} \sum_{j=0}^{\infty} \sum_{n=-\infty}^{\infty} iK_{zj+} \sin(k_{zij+}z) \frac{1}{D_{ABj}}
$$

× $[A_{nj}^1 T_{nhji}^{z2}(r) - A_{nj}^2 T_{nhji}^{z1}(r)]e^{-in\phi_h^q}e^{in\phi}$ (103)

$$
G_{HHi}^{\phi\phi} = \frac{1}{2\pi} \sum_{j=0}^{\infty} \sum_{n=-\infty}^{\infty} K_{zj+} \cos(k_{zij+}z) \frac{1}{D_{ABj}}
$$

× $[B_{nj}^2 T_{nhji}^{\phi1}(r) - B_{nj}^1 T_{nhji}^{\phi2}(r)]e^{-in\phi_k^q}e^{in\phi}$ (104)

$$
G_{HHi}^{\phi z} = \frac{1}{2\pi} \sum_{j=0}^{\infty} \sum_{n=-\infty}^{\infty} K_{zj+} \cos(k_{zij+}z) \frac{1}{D_{ABj}}
$$

× $[A_{nj}^1 T_{nhji}^{\phi 2}(r) - A_{nj}^2 T_{nhji}^{\phi 1}(r)]e^{-in\phi_{R}^q}e^{in\phi}$ (105)

$$
G_{HHi}^{\prime \phi} = \frac{1}{2\pi} \sum_{j=0}^{\infty} \sum_{n=-\infty}^{\infty} K_{zj+} \cos(k_{zij+}z) \frac{1}{D_{ABj}}
$$

× $[B_{nj}^2 T_{nhji}^{r1}(r) - B_{nj}^1 T_{nhji}^{r2}(r)]e^{-in\phi_{k}^q}e^{in\phi}$ (106)

$$
G_{HHi}^{rz} = \frac{1}{2\pi} \sum_{j=0}^{\infty} \sum_{n=-\infty}^{\infty} K_{zj+} \cos(k_{zij+}z) \frac{1}{D_{ABj}}
$$

× [A_n¹JT_{nhji}^r(r) - A_{nj}²T_{nhji}^r(r)]e^{-in ϕ_k^q e^{in ϕ}}

These expressions are quite a bit more involved than the 2-D dyadic Green's function formulas in Eqs. (56) to (58), with which the 3-D expressions in Eqs. (96), (104), and (106) are directly associated.

Three-Dimensional Inhomogeneous Soft Wall Case

The form of the dyadic Green's function elements for $r < R$ inside the ferrite puck is very similar to Eqs. (96) to (107) of the hard wall case, so they will not be provided here, but the elements for $r > R$ outside of the ferrite puck region will be given. Further information on the construction of these elements can be found in Krowne (9):

$$
G_{EHd}^{z\phi} = \frac{1}{2\pi} \sum_{j=0}^{\infty} \sum_{n=-\infty}^{\infty} f K_{zj}^{\phi} \cos(k_{zj}z) \frac{1}{D_{\overline{AB}j}} \left(\,{}^e_{z} A_{nj}^1 \overline{B}_{nj}^2 - \,{}^e_{z} A_{nj}^2 \overline{B}_{nj}^1 \right) \frac{K_n (\sigma_{\text{d}j}r)}{K_n (\sigma_{\text{d}j}R)} e^{in(\phi - \phi')} \tag{108}
$$

$$
G_{EHd}^{zz} = \frac{1}{2\pi} \sum_{j=0}^{\infty} \sum_{n=-\infty}^{\infty} f K_{zj}^{z} \cos(k_{zj}z) \frac{1}{D_{\overline{AB}j}} \left(^{e}_{z} A_{nj}^{2} \overline{A}_{nj}^{1} - \frac{e}{2} A_{nj}^{1} \overline{A}_{nj}^{2}\right) - \frac{e}{2} A_{nj}^{1} \overline{A}_{nj}^{2} \frac{K_{n} (\sigma_{\text{d}j}r)}{K_{n} (\sigma_{\text{d}j}R)} e^{in(\phi - \phi')} \tag{109}
$$

$$
G_{EHd}^{\prime\phi} = \frac{1}{2\pi} \sum_{j=1}^{\infty} \sum_{n=-\infty}^{\infty} i f K_{zj}^{\phi} \sin(k_{zj}z) \left(\frac{ins_j}{r D_{\overline{AB}j}} \left(\frac{hd}{r D_{\overline{AB}j}} \right) B_{nj}^2 \right)
$$

$$
- \frac{hd}{z} A_{nj}^2 \overline{B}_{nj}^1) \frac{K_n'(\sigma_{\text{d}}r)}{K_n(\sigma_{\text{d}}r)} \tag{110}
$$

$$
+\frac{inp_j}{rD_{\overline{AB}j}}(\mathscr{E}_A^1_{nj}\overline{B}^2_{nj}-\mathscr{E}_A^2_{nj}\overline{B}^1_{nj})\frac{K_n(\sigma_{dj}r)}{K_n(\sigma_{dj}R)}\Bigg)\;e^{in(\phi-\phi')}\\
$$

$$
G_{EHd}^{rz} = \frac{1}{2\pi} \sum_{j=1}^{\infty} \sum_{n=-\infty}^{\infty} i f K_{zj}^{z} \sin(k_{zj}z) \left(\frac{ins_{j}}{r D_{\overline{AB}j}} (h_{z}^{d} A_{nj}^{2} \overline{A}_{nj}^{1}) - h_{z}^{d} A_{nj}^{1} \overline{A}_{nj}^{2}) \frac{K_{n}'(\sigma_{dj}r)}{K_{n}(\sigma_{dj}R)} + \frac{p_{j} \sigma_{dj}}{D_{\overline{AB}j}} (\zeta^{e} A_{nj}^{2} \overline{A}_{nj}^{1} - \zeta^{e} A_{nj}^{1} \overline{A}_{nj}^{2}) \frac{K_{n}(\sigma_{dj}r)}{K_{n}(\sigma_{dj}R)} \right) e^{in(\phi - \phi')}
$$
\n(111)

$$
G_{EHd}^{\phi\phi} = \frac{1}{2\pi} \sum_{j=1}^{\infty} \sum_{n=-\infty}^{\infty} i f K_{zj}^{\phi} \sin(k_{zj}z) \left(\frac{-s_j}{D_{\overline{AB}j}} (h_{z}^{d} A_{nj}^{1} \overline{B}_{nj}^{2}) - h_{z}^{d} A_{nj}^{2} \overline{B}_{nj}^{1} \right) \frac{K_{n}'(\sigma_{dj}r)}{K_{n}(\sigma_{dj}R)} + \frac{inp_{j}\sigma_{dj}}{rD_{\overline{AB}j}} ({}_{z}^{e} A_{nj}^{1} \overline{B}_{nj}^{2} - {}_{z}^{e} A_{nj}^{2} \overline{B}_{nj}^{1}) \frac{K_{n}(\sigma_{dj}r)}{K_{n}(\sigma_{dj}R)} \right) e^{in(\phi-\phi')}
$$
\n(112)

$$
G_{EHd}^{\phi z} = \frac{1}{2\pi} \sum_{j=1}^{\infty} \sum_{n=-\infty}^{\infty} i f K_{zj}^{z} \sin(k_{zj}z) \left(\frac{-s_j \sigma_{dj}}{D_{\overline{AB}j}} (h_{z}^{d} A_{nj}^{2} \overline{A}_{nj}^{1}) - h_{z}^{d} A_{nj}^{1} \overline{A}_{nj}^{2} \right) \frac{K_{n}(\sigma_{dj}r)}{K_{n}(\sigma_{dj}R)}
$$

$$
+ \frac{inp_{j}}{r D_{\overline{AB}j}} ({}_{z}^{e} A_{nj}^{2} \overline{A}_{nj}^{1} - {}_{z}^{e} A_{nj}^{1} \overline{A}_{nj}^{2}) \frac{K_{n}(\sigma_{dj}r)}{K_{n}(\sigma_{dj}R)} \right) e^{in(\phi - \phi')}
$$
(113)

$$
G_{HHd}^{z\phi} = \frac{1}{2\pi} \sum_{j=1}^{\infty} \sum_{n=-\infty}^{\infty} i f K_{zj}^{\phi} \sin(k_{zj}z) \frac{1}{D_{\overline{AB}j}} ({}^{hd}_{z} A_{nj}^{1} \overline{B}_{nj}^{2})
$$

$$
- {}^{hd}_{z} A_{nj}^{2} \overline{B}_{nj}^{1}) \frac{K_{n} (\sigma_{\text{d}} j^{r})}{K_{n} (\sigma_{\text{d}} j^{R})} e^{in(\phi - \phi')}
$$
(114)

$$
G_{HHd}^{zz} = \frac{1}{2\pi} \sum_{j=1}^{\infty} \sum_{n=-\infty}^{\infty} i f K_{zj}^{z} \sin(k_{zj}z) \frac{1}{D_{\overline{AB}j}} {h_{zj}^{d} A_{nj}^{2} \overline{A}_{nj}^{1} - h_{z}^{d} A_{nj}^{1} \overline{A}_{nj}^{2} \overline{K}_{nj} (115)
$$
\n
$$
- \frac{h_{z}^{d} A_{nj}^{1} \overline{A}_{nj}^{2}}{K_{n} (\sigma_{dj} R)} e^{in(\phi - \phi')}
$$

$$
G_{HHd}^{\phi\phi} = \frac{1}{2\pi} \sum_{j=0}^{\infty} \sum_{n=-\infty}^{\infty} f K_{zj}^{\phi} \cos(k_{zj}z) \frac{1}{D_{\overline{AB}j}} {h d A_{nj}^1(r) \overline{B}_{nj}^2} - {h d A_{nj}^2(r) \overline{B}_{nj}^1} e^{in(\phi - \phi')}
$$
 (116)

$$
G_{HHd}^{\phi z} = \frac{1}{2\pi} \sum_{j=0}^{\infty} \sum_{n=-\infty}^{\infty} f K_{zj}^{z} \cos(k_{zj}z) \frac{1}{D_{\overline{A}\overline{B}j}} c_{\phi}^{h d} A_{nj}^{1}(r) \overline{A}_{nj}^{2}
$$

$$
- \frac{h d}{\phi} A_{nj}^{2}(r) \overline{A}_{nj}^{1} e^{in(\phi - \phi')}
$$
(117)

$$
G_{HHd}^{\prime\phi} = \frac{1}{2\pi} \sum_{j=1}^{\infty} \sum_{n=-\infty}^{\infty} i f K_{zj}^{\phi} \sin(k_{zj}z) \left(\frac{p_j \sigma_{dj}}{D_{\overline{AB}j}} (h_z^{\dagger} A_{nj}^{\dagger} \overline{B}_{nj}^2 - h_z^{\dagger} A_{nj}^{\dagger} \overline{B}_{nj}^{\dagger}) \overline{K_n(\sigma_{dj}r)} + \frac{inu_j}{r D_{\overline{AB}j}} ({}_{z}^{e} A_{nj}^{\dagger} \overline{B}_{nj}^2 - {}_{z}^{e} A_{nj}^{\dagger} \overline{B}_{nj}^{\dagger}) \overline{K_n(\sigma_{dj}r)} \right) e^{in(\phi - \phi')} + (118)
$$

$$
G_{HHd}^{rz} = \frac{1}{2\pi} \sum_{j=1}^{\infty} \sum_{n=-\infty}^{\infty} i f K_{zj}^{z} \sin(k_{zj}z) \left(\frac{p_j \sigma_{dj}}{D_{\overline{AB}j}} (h_z^{\text{d}} A_{nj}^{2} \overline{A}_{nj}^{1}) - h_z^{\text{d}} A_{nj}^{1} \overline{A}_{nj}^{2} \right) \frac{K_n' (\sigma_{dj}r)}{K_n (\sigma_{dj}R)}
$$

$$
+ \frac{inu_j}{r D_{\overline{AB}j}} ({}_{z}^{e} A_{nj}^{2} \overline{A}_{nj}^{1} - {}_{z}^{e} A_{nj}^{1} \overline{A}_{nj}^{2}) \frac{K_n (\sigma_{dj}r)}{K_n (\sigma_{dj}R)} \right) e^{in(\phi - \phi')}
$$
(119)

The 3-D dyadic Green's function formulas in Eqs. (108), (116), and (118) are directly associated with the 2-D expressions in Eqs. (59) to (61), which are much simpler.

CIRCULATOR METALLIZATION tity tensor,

Circulator structures realized in the laboratory and in industrial applications are made either with a single substrate or with several layers. The single substrate case obviously oc-
curs when the substrate and the ferrite material are one and
the same. But due to complications of mechanical and mate-
 $\frac{1}{2}$ and mate-
 $\frac{1}{2}$ and $\frac{1}{$ rial processing steps, several layers may exist. The designer can expect layers that do not exhibit nonreciprocal action to reduce the effectiveness of the finished circulator device when this layered effect shows up in the region under the shield. Structures that use pucks dropped into an existing substrate, whether of dielectric or of other ferrite material, will not suffer degradation in the main spatial operating region of the device. Film processes, which rely on deposition on top of an **LOSS CONTRIBUTIONS** existing semiconductor semiinsulating substrate, or on top of an insulator, will produce the layered effect under the shield.
It is possible to avoid this effect if the metal ground plane for
the device can be deposited on top of the substrate, thereby
with materials are utilized wit

mittivity. [Discussion about how to develop a self-consistent film on silicon substrate higher frequency X-band (10 GHz)
rigorous approach based on three dimensions is found in device has been calculated by Adam et al. (1

ships for the equivalent RF permittivity ϵ_{eq} and equivalent RF permeability tensor $\vec{\mu}_{eq}$ are

$$
\epsilon_{\text{eq}} = \frac{\epsilon_{\text{d}} \epsilon_{\text{f}}}{\epsilon_{\text{d}} \frac{d_{\text{f}}}{d} + \epsilon_{\text{f}} \frac{d_{\text{d}}}{d}} \tag{120}
$$

$$
\stackrel{\leftrightarrow}{\mu}_{\text{eq}} = \stackrel{\leftrightarrow}{\mu}_d \frac{d_d}{d} + \stackrel{\leftrightarrow}{\mu}_f \frac{d_f}{d} \tag{121}
$$

In Eq. (120), ϵ_d and ϵ_f are respectively the dielectric and ferrite permittivities. The total substrate thickness *d* is merely

$$
d = d_d + d_f \tag{122}
$$

expressions for complex μ and κ , and adding the subscript f to the tensor permeability to be absolutely unambiguous. The equation is true for small corrections, implicit in the whole dielectric permeability, a scalar (and assumed for simplicity derivation. What is placed in the formulas in Eq. (125) for μ

MULTIPLE LAYERS UNDER THE to be unity times the free space value), is upgraded to an iden-

$$
\stackrel{\leftrightarrow}{\mu}_{d} = \mu_{0} \stackrel{\leftrightarrow}{I} \tag{123}
$$

$$
\vec{\mu}_{\text{eq}} = \mu_0 \begin{bmatrix} \frac{d_d}{d} + \mu \frac{d_d}{d} & -j\kappa \frac{d_f}{d} & 0\\ j\kappa \frac{d_f}{d} & \frac{d_d}{d} + \mu \frac{d_d}{d} & 0\\ 0 & 0 & 1 \end{bmatrix}
$$
(124)

the device can be deposited on top of the substrate, thereby
bringing up the ground plane from below, and then depositing
tallic losses of the conductors constituting the circulator
the ferrite film.
Assuming that we have

a scaling procedure based on total area. The theory becomes essentially that of a parallel plate waveguiding situation.

The effective permeability within the ferrite region, assum- $\epsilon_{\text{eq}} = \frac{\epsilon_{\text{d}} \epsilon_{\text{f}}}{d_{\text{f}}}$ (120) The effective permeability within the ferrite ing an $e^{j\omega t}$ time dependence, from this theory is

$$
\mu_{\text{eq}} = \frac{\mu_{\text{f}}}{\left(1 - (1 - j)\frac{\delta}{d} \frac{\mu_{\text{m}}}{\mu_{\text{f}}}\right)^2}
$$
\n
$$
\approx \mu_{\text{f}} \left(1 + 2(1 - j)\frac{\delta}{d} \frac{\mu_{\text{m}}}{\mu_{\text{f}}}\right)
$$
\n(125)

Equation (125) provides an equivalent permeability for the ferrite region, which accounts for the whole circulator struc-Equation (121) arises from Eq. (1) on using the Polder tensor ture under the shield, the imperfect metal regions and the main ferrite puck region. The second approximation in the is the 2-D effective permeability for the ferrite. The ratio of skin depth to substrate thickness is δ/d , and μ_{m}/μ_{f} is the metal-to-ferrite permeability ratio.

The last thing to do is to obtain an effective propagation constant in the ferrite medium. It is found by invoking the first equality in Eq. (125):

$$
k_{\text{eq,p}} = k_{\text{eq,f}} = \omega \sqrt{\epsilon_{\text{f}} \mu_{\text{eq,f}}} = \omega \sqrt{\epsilon_{\text{f}} \mu_{\text{f}}} \frac{1}{1 - (1 - j)(\delta/d) / (\mu_{\text{m}}/\mu_{\text{f}})}
$$

$$
= k_{\text{f}} \frac{1}{1 - (1 - j)(\delta/d) / (\mu_{\text{m}}/\mu_{\text{f}})} \approx k_{\text{f}} \left(1 + (1 - j) \frac{\delta}{d} \frac{\mu_{\text{m}}}{\mu_{\text{f}}} \right)
$$
(126)

MATCHING SECTIONS

Self-consistent electromagnetic solvers work on the premise that specific driving conditions exist at each circulator port, Port 1 thereby exciting the internal fields of the device, sometimes
referred to as the intrinsic device. This is true whether the
solver is a Green's function method relying upon Dirac delta
solver is a Green's function method r function sources at the port locations, or a finite-element method relying upon imposed fields at the port locations. In either case, the tangential *E* and *H* fields at the port locations structure are found by mapping or transforming S ₂ through on the circulator device perimeter $r = R$ must obey continuity τ_{M} , yielding **S**. with the tangential E and H fields in the exiting port transmission lines. These microstrip transmission lines have impedance *Zk* for the *k*th port location, and their impedances are **NUMERICAL STUDIES AND COMPARISON** found by using the width determined from the extent of each **WITH EXPERIMENT** particular port and the common substrate thickness. For ports of identical angular extent, all Z_k will be the same (mak-

rators. Figure 3 shows a circuit sketch of a symmetrically dis-
posed three-port device, where at progressively increasing ra-
dial distance from the central circulator puck, the s-
parameter matrix goes from its intrinsi S_1 to its rereferenced $N \times N$ value $S_{re} = S_2$ to its final $N \times N$ value $S_m = S$ after encountering a matching section with a **Electromagnetic Fields and** *S* **Parameters** 2×2 transfer matrix T_M . This last matrix will generally be Consider characterizing sech individual

directly into the *s*-parameter calculation. Each microstrip transformer section is permitted to have a user-chosen length and width. Dissipation losses are included in each microstrip transformer section, so that the final *s* parameters calculated include all intrinsic as well as extrinsic device losses. This is important for wide-bandwidth circulators having many quar- where $N_1^d = 3$, and $H_{dc}(R, \phi)$ are the magnetic field sources ter-wavelength matching sections, because the matching sec- driving the device. Equation (127) gives the electric field anytion losses frequently are greater than the intrinsic device where within the puck. Sources $H_{\alpha}(R, \phi)$ at the perimeter of

ports of identical angular extent, all Z_k will be the same (mak-
ing $Z_k = Z_0$, $k = 1, 2, ..., N$). The *s* parameters of the intrin-
sic circulator are referenced to these impedances, or imped-
ance if they are all the same. To facilitate the incorporation of the circulator device into
a CAD program generating s parameters, the N-port device
should be rereferenced to the system impedances Z'_k in use.
 Z'_k , $k = 1, 2, ..., N$, will usually be 50

 2×2 transfer matrix \mathbf{T}_M . This last matrix will generally be
referenced to the system matrix impedance Z_0 .
Matching circuits for microstrip circulators are most com-
monly cascaded sections of transformers, usu

$$
E_z(r,\phi) = \sum_{q=1}^{N_{\rm T}^{\rm d}} G_{EH}^{z\phi}(r,\phi;R,\phi^{\rm q}) H_{\phi\rm c}(R,\phi^{\rm q}) \,\Delta\phi^{\rm q} \tag{127}
$$

losses. The final matched *s* parameters for the circulator the device may be found self-consistently with the internal

electromagnetic behavior of the puck and the external circuit network by using the loading conditions

$$
\frac{E_{z(\text{in})}^{\text{a}}}{H_{\text{a(in)}}} = \zeta_{\text{a}}
$$
 (128)

$$
\frac{E_{z(\text{out})}^{\text{b}}}{H_{\text{b(out)}}} = -\zeta_{\text{b}} \tag{129}
$$

$$
\frac{E_{z(\text{out})}^{\text{c}}}{H_{c(\text{out})}} = -\zeta_{\text{c}} \tag{130}
$$

The internal electromagnetic behavior within the puck is evaluated at the circulator perimeter by setting $r = R$ in Eq. (127). Next we absorb the azimuthal spread of each port into the Green's function by defining a streamlined dyadic Green's **Figure 4.** Top view of the a circulator metallization pattern used in

$$
G(\phi, \phi_{\mathbf{q}}) = G_{EH}^{z\phi}(R, \phi; R, \phi_{\mathbf{q}}) \Delta \phi_{\mathbf{q}}
$$
(131)

where the understood indices and arguments have been $R = 0.279 \ w_1 = 0.096 \ cm, \ w_2 = 0.030 \ cm$ (50 Ω transmission line), dropped. The convenient form in Eq. (131) is now used to expand Eq. (127) at the perimeter:

$$
E_z(R, \phi) = G(\phi, \phi_a)H_{\phi a} + G(\phi, \phi_b)H_{\phi b} + G(\phi, \phi_c)H_{\phi c}
$$
 (132)

Now evaluate Eq. (132) at each of the ports, $q = a$, b, c, la- should look like. Calculations reported here use the one-stage beled counterclockwise, and simplify the notation for $E_z(R, \phi)$ transformer section shown in the figure. Figure 5 gives a realto E^q by setting $\phi = \phi_q$.

$$
E_z^a = G(\phi_a, \phi_a) H_{\phi a} + G(\phi_a, \phi_b) H_{\phi b} + G(\phi_a, \phi_c) H_{\phi c}
$$
 (133)

$$
E_z^{\rm b} = G(\phi_{\rm b}, \phi_{\rm a}) H_{\phi{\rm a}} + G(\phi_{\rm b}, \phi_{\rm b}) H_{\phi{\rm b}} + G(\phi_{\rm b}, \phi_{\rm c}) H_{\phi{\rm c}} \tag{134}
$$

$$
E_z^c = G(\phi_c, \phi_a)H_{\phi a} + G(\phi_c, \phi_b)H_{\phi b} + G(\phi_c, \phi_c)H_{\phi c}
$$
 (135)

Once the $H_{\phi i}$ fields ($i = a, b, c$) have been found from Eqs. stead, the field seen by the circulator is dependent upon the (128) to (130) and (133) to (135), the *s* parameters can be obtained from

$$
s_{11} = 1 - \zeta_a H_a \tag{136}
$$

$$
s_{21} = E_z^{\rm b} = -\zeta_{\rm b} H_{\rm b} \tag{137}
$$

$$
s_{31} = E_z^{\rm c} = -\zeta_c H_c \tag{138}
$$

Equation (127) provides the recipe for computing the electric field distribution within the circulator puck. The two magnetic field components H_r , H_ϕ may also be sought from dyadic Green's function expansions similar to Eq. (127).

Circulator Performance and Field Contour Plots

The circulator port impedances (looking into the device) are generally quite a bit lower than the standard 50 Ω reference impedance system. Because of this problem, actual circulator devices prepared in industry for insertion into circuits need **Figure 5.** Example of the variation of the demagnetization factor transition networks between the circulator puck perimeter N_x with radial distance from the puck center for an X-band device.

function element actual calculations for a nominal 8 GHz X-band device. Outside the puck shield are three identical quarter-wave transformers, which transition to narrower microstrip lines. The substrate is Trans-Tech *G*113, $4\pi M_s = 1780$ G, $\Delta H = 45$ Oe, $\epsilon_r = 15.0$, tan $\delta = 0.0002$, substrate thickness = 0.051 cm, and conductor thickness = 0.0005 cm.

E and the final circuit to be matched. Figure 4 and the previous discussion indicate how this matching process is accomplished. Figure 4 shows a top view of what the metallization *istic variation of the demagnetizing factor* N_{zz} *expected in an* actual device. It is fairly constant (80% to 90%) until the edge *E* of the puck is approached (within 70% of the edge in terms of the total radius); then the value dives to 45%. It is this very $\text{nonlinear change in } N_{zz}$ that makes the partitioning of the puck necessary and the recursive dyadic Green's function invaluable for correct modeling of the circulator. The applied magnetic bias field, a static field, is not always constant. In-

Figure 6. Example of the variation of the applied external bias field H_{app} with radial distance from the puck center for an X-band device.

Numerical robustness depends upon the convergence behavior of the solution and the computation time to determine the solution. Figure 7 provides a plot, for an inhomogeneous

formation on convergence under unity incremental variation answer is accurate to within ± 0.1 dB of the final value.

Figure 8. Convergence behavior of isolation versus n_{max} at two frequencies, 7 GHz and 9 GHz, selected from a diagram such as in Fig. precise magnet location and the attendant magnetic circuitry. 7, but for a uniform case. A single quarter-wavelength transformer is The shape of H_{ap} might look like that seen in Fig. 6. utilized in the matching network at each port. Results are given in a Numerical robustness depends upon the convergence be. 50Ω reference system.

circulator, of the isolation s_{31} against frequency for six trun- of n_{max} . This is given for a uniform device in Figs. 8 and 9, cated cases of the doubled-sided infinite azimuthal summa- which show the results at two selected microwave frequencies tions used in the dyadic Green's function evaluations. The for, respectively, a matched circulator and an intrinsic (or maximum azimuthal index used is denoted by n_{max} , and we bare) circulator. The two frequencies straddle the 8 GHz censhow $n_{\text{max}} = 3, 6, 9, 18, 36, 72$ for the X-band device. n_{max} must ter frequency. Clearly, in comparing Figs. 8 and 9, we see that be at least 18 before the solution is within ± 0.25 dB of the the introduction of matching transformers causes significant final value. For a uniform device *n*max may be chosen smaller numerical oscillation to occur. This is not entirely unexpected, to obtain similar accuracy. For example, $n_{\text{max}} = 9$ yields con- considering the manner in which a transformer operates. vergence to within ± 0.40 dB of the final value for the uni- Convergence behavior with respect to the number of computaform device. tional regions, *N*_R, which is equal to the number of annuli, Figure 7 gives an overall idea of what happens over the *N*, plus one $(N_R = N + 1)$, is shown in Fig. 10 for $N_R = 1, 6$, entire circulator bandwidth, but fails to provide detailed in- 16, 50. For $N_R = 6$ or greater, the numerically determined

Figure 7. Isolation s_{31} versus frequency, with the curves parametrized in terms of n_{max} , the maximum azimuthal index number. A single ferrite material is used for the circulator puck, with a five-region model (one central disk plus four annuli) employed to repre sent the demagnetizing factor N_{zz} .

Figure 9. Convergence behavior of isolation versus n_{max} at two fre-
quencies, 7 GHz and 9 GHz, selected from a diagram such as in Fig. lation on a nominal 8 GHz circulator versus the number of regions, ferrite disk is present). Results are given in a 50 Ω reference system. added afterward.

trized in terms of the number of regions $N_R (= N + 1)$ used to model tory. The null gets partial
the demagnetizing factor N_m . the demagnetizing factor N_{zz} .

lation on a nominal 8 GHz circulator versus the number of regions, 7, but for a uniform case. No transformer is utilized (only a central N_R . The inner disk is counted as the first region, with outlying annuli

The particular dyadic Green's function types covered in culator are in excellent agreement. Good agreement also exthis presentation can be evaluated extremely efficiently using ists for calculated and measured return loss, with a slight FORTRAN computer codes. That this is so becomes apparent discrepancy between the minimum points. Acceptable when studying Fig. 11, which plots computation time in sec- agreement is found for calculated and measured isolation reonds per frequency point against the number of regions, N_R . sults, with the calculated results somewhat more favorable Run times are for execution on a Macintosh Quadra 650. The than actually seen in the lab. At the minimum point, the calcost in time of using more regions increases nearly linearly at culated value is 9 dB better. Imperfections in the fabricated and beyond $N_R = 2$. The algorithmic difference for $N_R = 1$ has device may account for much of the deviation seen between caused the initial decrease before the general trend becomes numerical calculation and experiment in Fig. 12. The onset of evident. the next puck resonance causes the obvious glitches in the Use of the 2-D recursive Green's function computer code experimental curves between 12 GHz and 13 GHz at the high for the inhomogeneous situation allows comparison in Fig. 12 end of the operating band. Careful examination of the calcuof measured and calculated (a) insertion loss *s*²¹ and return lated curves shows evidence of this next resonance (small inloss s_{11} and (b) isolation s_{31} versus frequency. It is seen that flections, rises, and dips). The significant difference seen here the calculated and measured insertion loss for the X-band cir- between theory and experiment is most likely due to the large measured ferromagnetic linewidth $\Delta H = 320$ Oe assigned to the ferrite material used to fabricate the circulator. Reduction of ΔH makes the calculated and experimental results very similar. Direct visual evidence of this next resonance is provided in field patterns to be discussed shortly in Fig. 14.

Figures $13(a-c)$ show electric field patterns for the intrinsic inhomogeneous circulator (without any matching structures), calculated by the 2-D recursive Green's function computer code using an incident signal at each of the three ports with no incoming signal at the remaining two ports. When embedding the intrinsic device in a matching network, the actual electric field pattern obtained is shown in Fig. 13(d). Port loads attached to the circulator at each port are shown in Fig. 13(e). Each load consists of a quarter-wave matching network section and the system impedance. A null in the electric field pattern (lightest oval region) occurs in the first three panels of Fig. $13(a-c)$, but these nulls are not at the perimeter. They appear inside the puck for each port excitation case. Only in the matched device, which is excited essentially like (a), do we see a movement of the null to the perimeter, where **Figure 10.** Isolation s_{31} versus frequency with the curves parame- it creates the very low desired isolation seen in the laboratrized in terms of the number of regions $N_R (= N + 1)$ used to model tory. The null gets par

Figure 12. Measured and calculated (a) insertion loss s_{21} and return loss s_{11} and (b) isolation s_{31} versus frequency, using recursive Green's function computer code. $4\pi M_s = 2300 \text{ G}, H_{\text{an}} = 2300$ Oe, $\Delta H = 320$ Oe, $h = 0.635$ mm, $R = 2.7026$ mm, $w = 1.6561$ mm, $w_c = 1.4w$, $\epsilon_f = 13.3$, $\epsilon_d =$ 9.5, tan δ = 0.0003, and center frequency $f = 9.5$ GHz. (Device fabricated at EMS Technologies, Inc. by David Popelka and Gordon Harrison.)

A comment about the way the plots were constructed in The electric field pattern variation with frequency from 5 Fig. 13 (and the following Fig. 14) is appropriate here. The GHz to 13 GHz was calculated by using the 2-D re has field magnitudes below this tiny value, and inside its con- second null, both located within the puck. tour toward its center the values approach zero. Successive contours encircling ever larger regions or moving further away from the null correspond to 15%, 25%, 35%, 45%, 55%, **FUTURE DEVELOPMENTS** 65%, 75%, 85%, and 95% of the maximum electric field value. Increasing darkness denotes increasing magnitude of the There are other important and interesting subjects we have electric field. For example, the uniformly shaded region be- not been able to touch upon in this short summary. For examtween the 35% and 45% contours must have $0.35|E_{z,\text{max}}| \leq |E_z|$ ple, symmetry considerations shown in Krowne (16) enable

GHz to 13 GHz was calculated by using the 2-D recursive interface between neighboring uniformly shaded regions rep- Green's function computer code and is shown in Fig. 14. resents a contour line of constant electric field magnitude. Clockwise movement of the null, getting closer to the device The first such line, encircling the lightest region, corresponds perimeter, is seen before the center frequency (about 9 GHz) to 5% of the maximum value attained within the puck. We is attained. Once the center frequency is passed, the null have referred to the lightest region as the "null" because it pulls away from the perimeter, shrinks in size, and spawns a

 $\leq 0.45|E_{z_{\text{max}}}|$.

Figure 13. Electric field patterns for the intrinsic circulator (without any matching structures) as calculated by the 2-D recursive Green's function computer code using an incident signal at (a) port 1, (b) port 2, and (c) port 3, with no incoming signal at the remaining two ports for each case. (d) Electric field pattern obtained by immersing the intrinsic device in a matching network, consisting of individual port loads shown in (e). Shading indicates electric field magnitude, with the darkest region having

Figure 14. Electric field patterns for the intrinsic circulator embedded in a matching network are calculated by the 2-D recursive Green's function computer code, and displayed at nine individual frequencies. Shading indicates electric field magnitude, with the darkest region being the highest magnitude.

on the number of Green's functions that must be evaluated to NJ: Prentice-Hall, 1960. determine the *s* parameters (perimeter dyadic Green's func- 3. H. S. Newman and C. M. Krowne, Analysis of ferrite circulators tions) and the electromagnetic fields (internal and external by 2-D finite element and recursive Green's function techniques,
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Circulators are pivotal components in electronic equip-
ment, and their use in potentially huge quantities in automo-
meous circular ferrite circulator, IEEE Microw. Theory Technol. tive and train distance ranging units, as well as other com-
mercial ventures, may herald a promising future beyond what
a CM Krowne, Femite mismetrin eigential states of mercial ventures, may herald a promising future beyond what b. C. M. Krowne, Ferrite microstrip circulator 3D dyadic Green's seems to be developing for military applications. CAD will function with perimeter interfacial wa play a critical role in these applications by allowing circula- neity, *Microw. Opt. Technol. Lett.,* **15** (4): 235–242, 1997. tors to be rapidly designed to suit various requirements. Nu-
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